

# PolarHV™ Power MOSFET

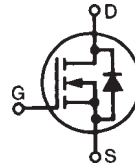
**IXTQ 22N60P**  
**IXTV 22N60P**  
**IXTV 22N60PS**

$V_{DSS} = 600 \text{ V}$   
 $I_{D25} = 22 \text{ A}$   
 $R_{DS(on)} \leq 330 \text{ m}\Omega$

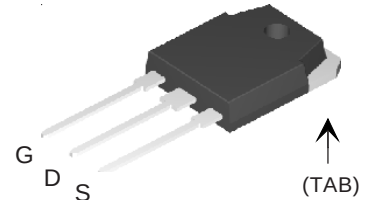
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N-Channel Enhancement Mode

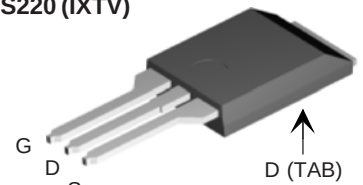
Preliminary Data Sheet



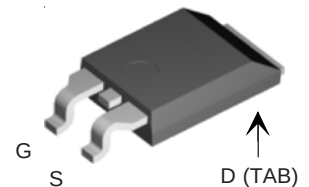
TO-3P (IXTQ)



PLUS220 (IXTV)



PLUS220SMD (IXTV\_S)



G = Gate      D = Drain  
S = Source    TAB = Drain

| Symbol    | Test Conditions                                                                                                                         | Maximum Ratings |                                      |
|-----------|-----------------------------------------------------------------------------------------------------------------------------------------|-----------------|--------------------------------------|
| $V_{DSS}$ | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                                                                                         | 600             | V                                    |
| $V_{DGR}$ | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 1 \text{ M}\Omega$                                                          | 600             | V                                    |
| $V_{GS}$  | Continuous                                                                                                                              | $\pm 20$        | V                                    |
| $V_{GSM}$ | Tranisient                                                                                                                              | $\pm 30$        | V                                    |
| $I_{D25}$ | $T_C = 25^\circ\text{C}$                                                                                                                | 22              | A                                    |
| $I_{DM}$  | $T_C = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$                                                                              | 66              | A                                    |
| $I_{AR}$  | $T_C = 25^\circ\text{C}$                                                                                                                | 22              | A                                    |
| $E_{AR}$  | $T_C = 25^\circ\text{C}$                                                                                                                | 40              | mJ                                   |
| $E_{AS}$  | $T_C = 25^\circ\text{C}$                                                                                                                | 1.0             | J                                    |
| $dv/dt$   | $I_S \leq I_{DM}$ , $di/dt \leq 100 \text{ A}/\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ ,<br>$T_J \leq 150^\circ\text{C}$ , $R_G = 4 \Omega$ | 10              | V/ns                                 |
| $P_D$     | $T_C = 25^\circ\text{C}$                                                                                                                | 400             | W                                    |
| $T_J$     |                                                                                                                                         | -55 ... +150    | $^\circ\text{C}$                     |
| $T_{JM}$  |                                                                                                                                         | 150             | $^\circ\text{C}$                     |
| $T_{stg}$ |                                                                                                                                         | -55 ... +150    | $^\circ\text{C}$                     |
| $T_L$     | 1.6 mm (0.062 in.) from case for 10 s<br>Plastic body for 10 s                                                                          | 300<br>250      | $^\circ\text{C}$<br>$^\circ\text{C}$ |
| $M_d$     | Mounting torque (TO-3P)                                                                                                                 | 1.13/10         | Nm/lb.in.                            |
| Weight    | TO-3P                                                                                                                                   | 6               | g                                    |
|           | PLUS220 & PLUS220SMD                                                                                                                    | 5.0             | g                                    |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified)                                      | Characteristic Values |      |                      |
|--------------|------------------------------------------------------------------------------------------------------------------|-----------------------|------|----------------------|
|              |                                                                                                                  | Min.                  | Typ. | Max.                 |
| $V_{DSS}$    | $V_{GS} = 0 \text{ V}$ , $I_D = 250 \mu\text{A}$                                                                 | 600                   |      | V                    |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 250 \mu\text{A}$                                                                      | 3.0                   |      | 5.0 V                |
| $I_{GSS}$    | $V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$                                                                       |                       |      | $\pm 100 \text{ nA}$ |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$                                                                                               |                       |      | 25 $\mu\text{A}$     |
|              | $V_{GS} = 0 \text{ V}$ $T_J = 125^\circ\text{C}$                                                                 |                       |      | 250 $\mu\text{A}$    |
| $R_{DS(on)}$ | $V_{GS} = 10 \text{ V}$ , $I_D = 0.5 I_{D25}$<br>Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $d \leq 2 \%$ |                       |      | 330 $\text{m}\Omega$ |

## Features

- International standard packages
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect

## Advantages

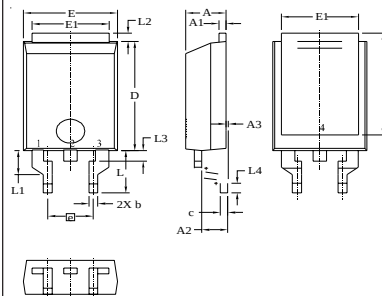
- Easy to mount
- Space savings
- High power density

| Symbol       | Test Conditions                                                                             | Characteristic Values                               |      |      |
|--------------|---------------------------------------------------------------------------------------------|-----------------------------------------------------|------|------|
|              |                                                                                             | (T <sub>j</sub> = 25°C, unless otherwise specified) |      |      |
|              |                                                                                             | Min.                                                | Typ. | Max. |
| $g_{fs}$     | $V_{DS} = 20\text{ V}; I_D = 0.5 I_{D25}$ , pulse test                                      | 15                                                  | 21   | S    |
| $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$                               |                                                     | 3600 | pF   |
| $C_{oss}$    |                                                                                             |                                                     | 305  | pF   |
| $C_{rss}$    |                                                                                             |                                                     | 38   | pF   |
| $t_{d(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = I_{D25}$<br>$R_G = 4\ \Omega$ (External) |                                                     | 20   | ns   |
| $t_r$        |                                                                                             |                                                     | 20   | ns   |
| $t_{d(off)}$ |                                                                                             |                                                     | 60   | ns   |
| $t_f$        |                                                                                             |                                                     | 23   | ns   |
| $Q_{g(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$                             |                                                     | 105  | nC   |
| $Q_{gs}$     |                                                                                             |                                                     | 25   | nC   |
| $Q_{gd}$     |                                                                                             |                                                     | 55   | nC   |
| $R_{thJC}$   | (TO-3P)                                                                                     |                                                     | 0.31 | K/W  |
| $R_{thCK}$   |                                                                                             |                                                     | 0.21 | K/W  |

## Source-Drain Diode

| Symbol   | Test Conditions                                                                                       | Characteristic Values                               |      |               |
|----------|-------------------------------------------------------------------------------------------------------|-----------------------------------------------------|------|---------------|
|          |                                                                                                       | (T <sub>j</sub> = 25°C, unless otherwise specified) |      |               |
|          |                                                                                                       | min.                                                | typ. | max.          |
| $I_S$    | $V_{GS} = 0\text{ V}$                                                                                 |                                                     |      | 22 A          |
| $I_{SM}$ | Repetitive                                                                                            |                                                     |      | 66 A          |
| $V_{SD}$ | $I_F = I_S, V_{GS} = 0\text{ V}$ ,<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |                                                     |      | 1.5 V         |
| $t_{rr}$ | $I_F = 22\text{ A}$<br>$-di/dt = 100\text{ A}/\mu\text{s}$<br>$V_R = 100\text{ V}$                    |                                                     | 410  | ns            |
| $Q_{RM}$ |                                                                                                       |                                                     | 4.0  | $\mu\text{C}$ |

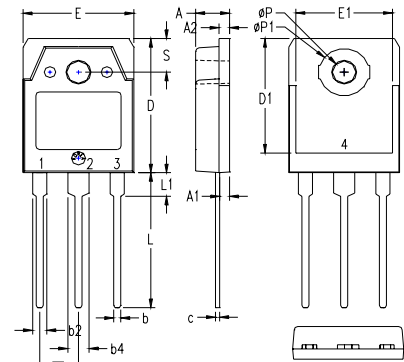
## PLUS220SMD



Terminals: 1 - Gate 2 - Drain  
3 - Source TAB - Drain

| SYM | INCHES  |      | MILLIMETER |       |
|-----|---------|------|------------|-------|
|     | MIN     | MAX  | MIN        | MAX   |
| A   | .169    | .185 | 4.30       | 4.70  |
| A1  | .028    | .035 | 0.70       | 0.90  |
| A2  | .098    | .118 | 2.50       | 3.00  |
| A3  | .000    | .010 | 0.00       | 0.25  |
| b   | .035    | .047 | 0.90       | 1.20  |
| c   | .028    | .035 | 0.70       | 0.90  |
| D   | .551    | .591 | 14.00      | 15.00 |
| D1  | .512    | .539 | 13.00      | 13.70 |
| E   | .394    | .433 | 10.00      | 11.00 |
| E1  | .331    | .346 | 8.40       | 8.80  |
| e   | .200BSC |      | 5.08       | BSC   |
| L   | .209    | .228 | 5.30       | 5.80  |
| L1  | .118    | .138 | 3.00       | 3.50  |
| L2  | .035    | .051 | 0.90       | 1.30  |
| L3  | .047    | .059 | 1.20       | 1.50  |
| L4  | .039    | .059 | 1.00       | 1.50  |

## TO-3P (IXTQ) Outline

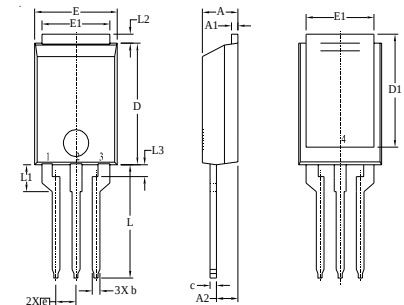


1 - GATE  
2 - DRAIN (COLLECTOR)  
3 - SOURCE (EMITTER)  
4 - DRAIN (COLLECTOR)

| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .185     | .193 | 4.70        | 4.90  |
| A1  | .051     | .059 | 1.30        | 1.50  |
| A2  | .057     | .065 | 1.45        | 1.65  |
| b   | .035     | .045 | 0.90        | 1.15  |
| b2  | .075     | .087 | 1.90        | 2.20  |
| b4  | .114     | .126 | 2.90        | 3.20  |
| c   | .022     | .031 | 0.55        | 0.80  |
| D   | .780     | .791 | 19.80       | 20.10 |
| D1  | .665     | .677 | 16.90       | 17.20 |
| E   | .610     | .622 | 15.50       | 15.80 |
| E1  | .531     | .539 | 13.50       | 13.70 |
| e   | .215 BSC |      | 5.45        | BSC   |
| L   | .779     | .795 | 19.80       | 20.20 |
| L1  | .134     | .142 | 3.40        | 3.60  |
| L2  | .126     | .134 | 3.20        | 3.40  |
| L3  | .272     | .280 | 6.90        | 7.10  |
| S   | .193     | .201 | 4.90        | 5.10  |

All metal area are tin plated.

## PLUS220 (IXTV) Outline



Terminals: 1 - Gate 2 - Drain  
3 - Source TAB - Drain

| SYM | INCHES   |      | MILLIMETER |       |
|-----|----------|------|------------|-------|
|     | MIN      | MAX  | MIN        | MAX   |
| A   | .169     | .185 | 4.30       | 4.70  |
| A1  | .028     | .035 | 0.70       | 0.90  |
| A2  | .098     | .118 | 2.50       | 3.00  |
| b   | .035     | .047 | 0.90       | 1.20  |
| c   | .028     | .035 | 0.70       | 0.90  |
| D   | .551     | .591 | 14.00      | 15.00 |
| D1  | .512     | .539 | 13.00      | 13.70 |
| E   | .394     | .433 | 10.00      | 11.00 |
| E1  | .331     | .346 | 8.40       | 8.80  |
| e   | .100 BSC |      | 2.54       | BSC   |
| L   | .512     | .551 | 13.00      | 14.00 |
| L1  | .118     | .138 | 3.00       | 3.50  |
| L2  | .035     | .051 | 0.90       | 1.30  |
| L3  | .047     | .059 | 1.20       | 1.50  |

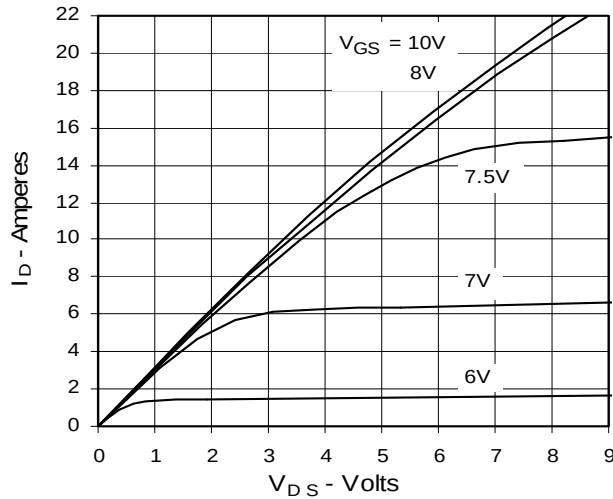
IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

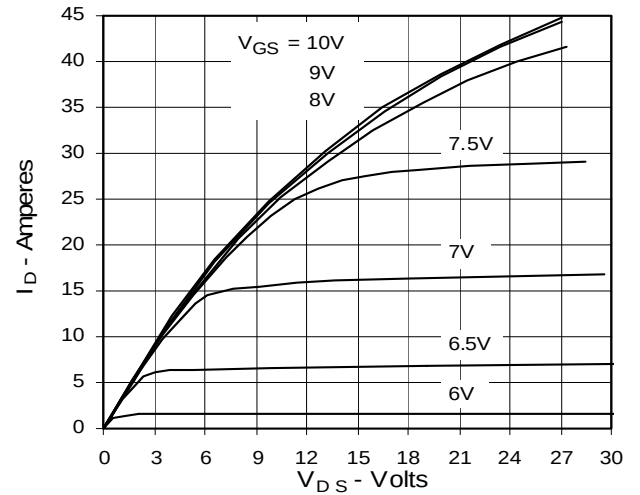
|           |           |           |           |              |              |
|-----------|-----------|-----------|-----------|--------------|--------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 |
| 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    |

|              |           |
|--------------|-----------|
| 6,683,344    | 6,727,585 |
| 6,710,405 B2 | 6,759,692 |
| 6,710,463    |           |

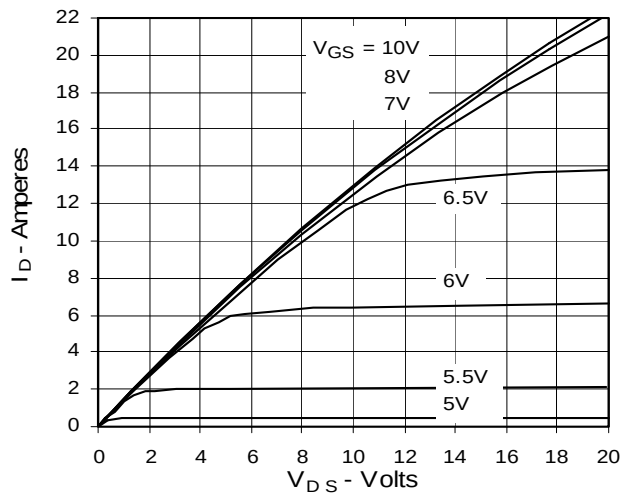
**Fig. 1. Output Characteristics**  
@ 25°C



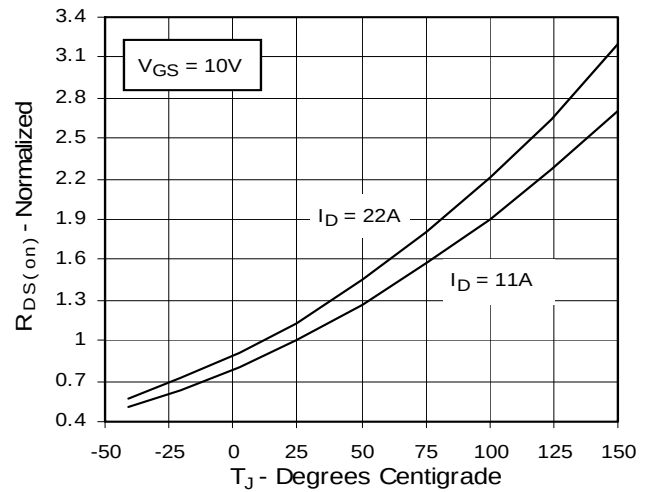
**Fig. 2. Extended Output Characteristics**  
@ 25°C



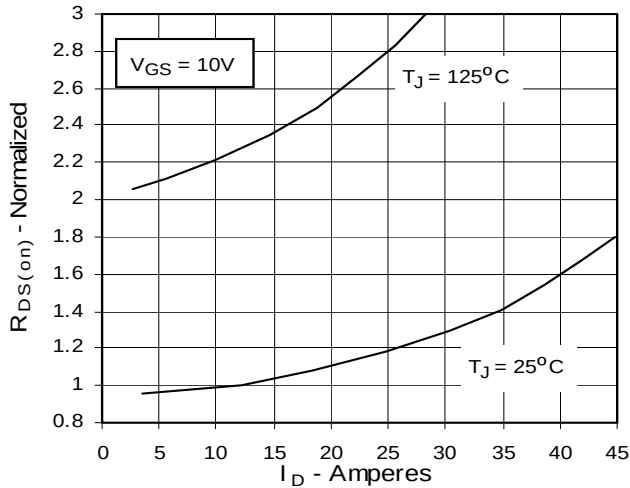
**Fig. 3. Output Characteristics**  
@ 125°C



**Fig. 4.  $R_{DS(on)}$  Normalized to 0.5  $I_{D25}$  Value vs. Junction Temperature**



**Fig. 5.  $R_{DS(on)}$  Normalized to 0.5  $I_{D25}$  Value vs.  $I_D$**



**Fig. 6. Drain Current vs. Case Temperature**

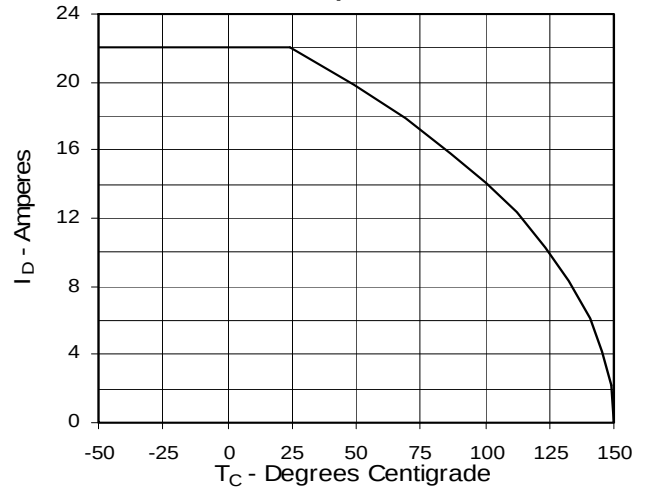


Fig. 7. Input Admittance

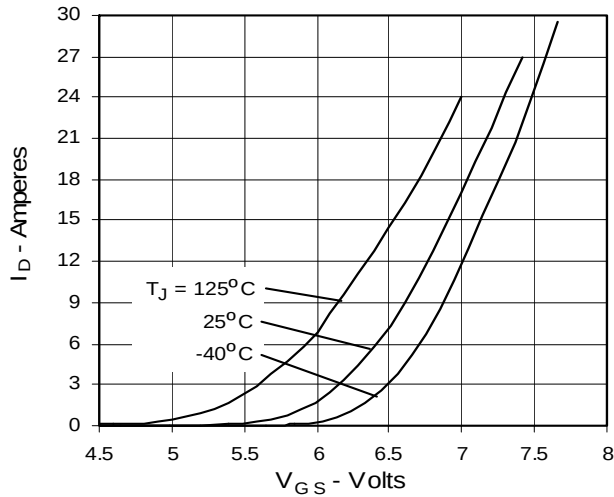


Fig. 8. Transconductance

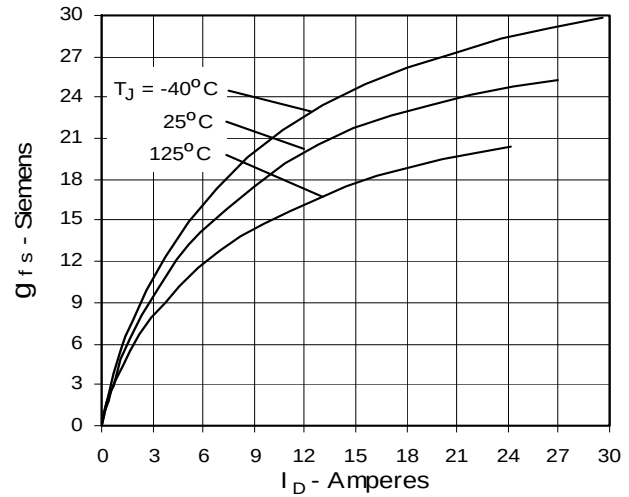


Fig. 9. Source Current vs. Source-To-Drain Voltage

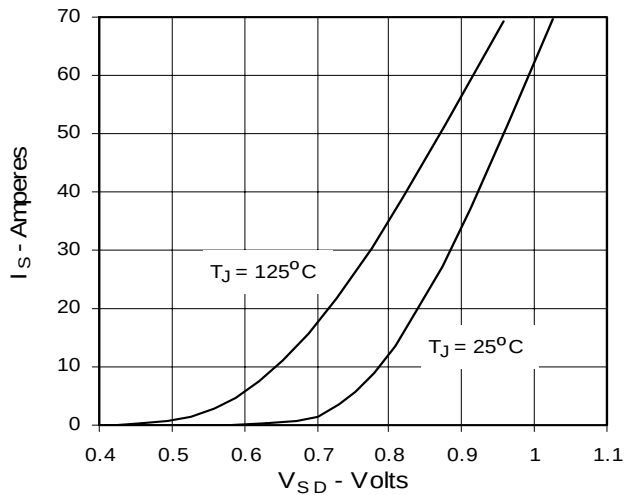


Fig. 10. Gate Charge

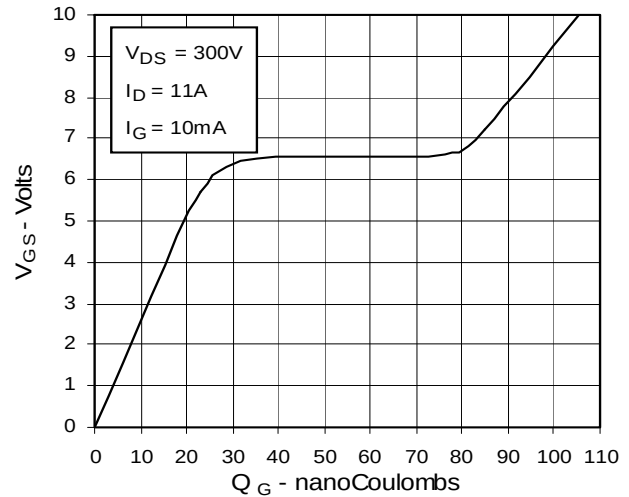


Fig. 11. Capacitance

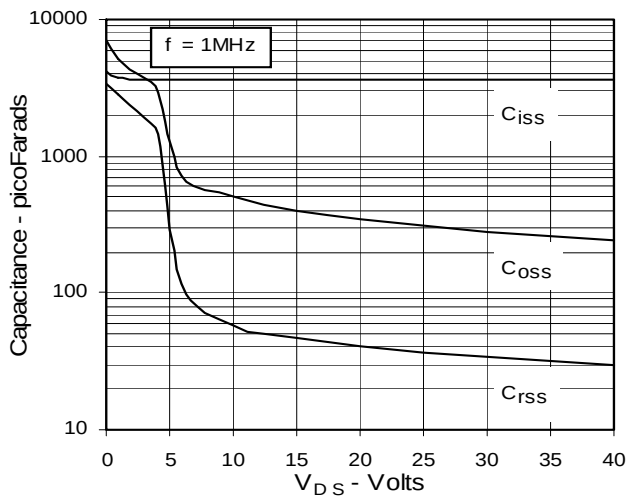


Fig. 12. Forward-Bias Safe Operating Area

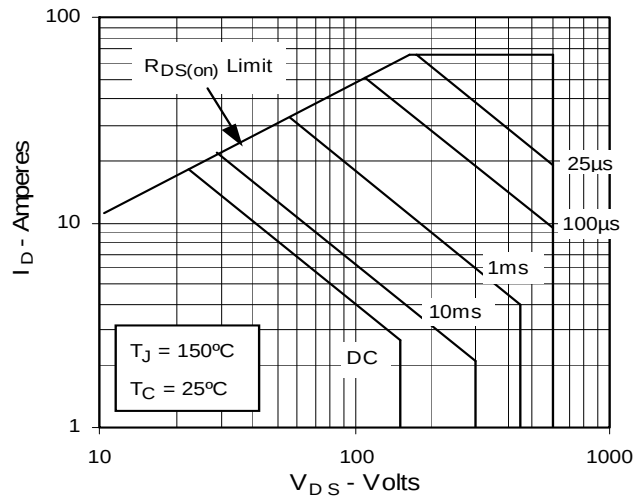


Fig. 13. Maximum Transient Thermal Resistance

